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## LEVEL-SHIFTED VACUUM FLUORESCENT DISPLAY DRIVERS

**DI-503B**

**DI-504B**

**DI-508B**

**DI-509B**

**DI-513B**

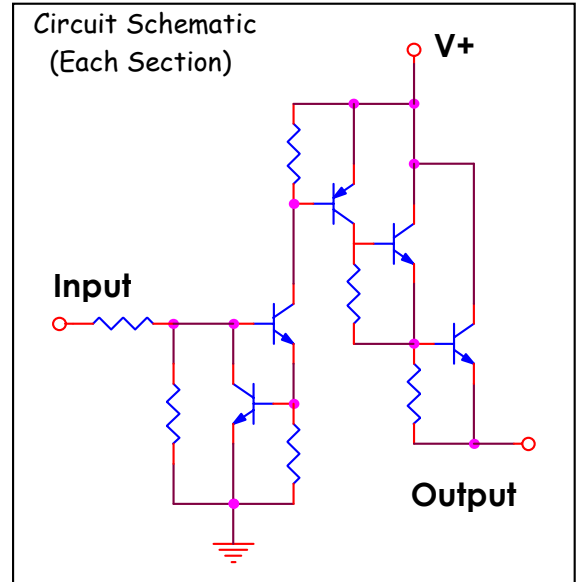
**DI-514B**

### General Description:

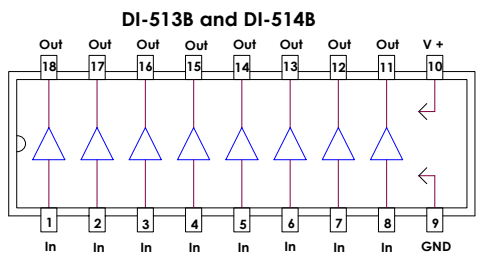
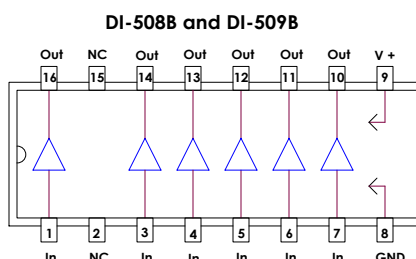
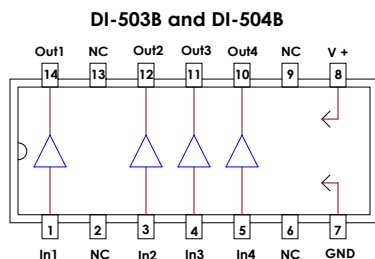
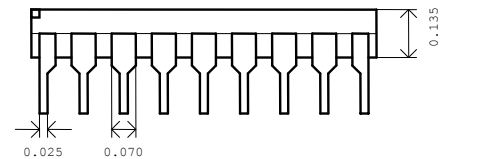
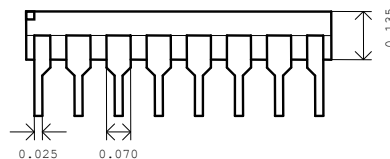
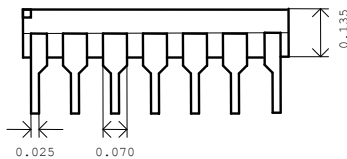
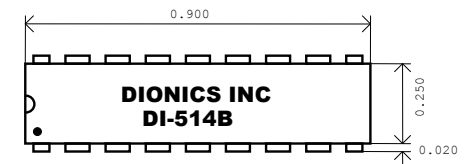
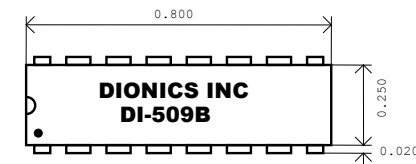
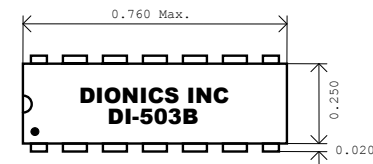
The DIONICS DI-513B and DI-514B series circuits are designed for interfacing between MOS or TTL circuitry and vacuum fluorescent display panels. Each section of these devices consists of a switched constant current level shifter-capable of 50 Volt or 80 Volt- operation and a PNP-NPN driver transistor pair. The constant current operation of the level shifter stage results in low power dissipation. Input circuitry is suitable for open drain PMOS, CMOS, open-collector or standard TTL.

### Features:

- ✓ 50V and 80V Level Shift Capability.
- ✓ MOS and TTL Compatibility
- ✓ 4 -, 6 - and 8-line Versions
- ✓ Segment and Digit Drivers
- ✓ Low Power Dissipation
- ✓ Reliable Dielectric Isolation Process



### Package Layout:



### Absolute Maximum Rating (Ta = 25 °C)

Characteristic	Symbol	Notes	Limits		Units
			DI-504B DI-509B DI-514B	DI-503B DI-508B DI-513B	
Supply Voltage	V +	Measured With Respect to GND	50	80	V
Input Voltage	V <sub>in</sub>	Measured With Respect to GND	35	35	V
Output Voltage	V <sub>out</sub>	Measured With Respect to V + Terminal	50	80	V
Output Current	I <sub>out</sub>		30	30	mA
Power Dissipation:	P <sub>D</sub>	Derate at DI-514B; DI-513B: 8 mW/°C Derate at DI-509B; DI-508B: 6 mW/°C Above 25°C Ambient	600	600	mW
Storage Temperature	T <sub>s</sub>		-55 to 125		°C
Operating Temperature	T <sub>o</sub>		0 to 70		°C

### Electrical Characteristics (Ta = 25 °C)

Parameter	Symbol	Notes	Conditions	Typ.	Max.	Units
Output Saturation Voltage * DI-509B; DI-514B; DI-504B * DI-508B; DI-513B; DI-503B.	V <sub>out</sub> (SAT)	Measured With Respect to V+ Terminal.  V+ = 50V ----- V+ = 80V	I <sub>o</sub> = 10mA; V <sub>i</sub> = 2.4V	1.5	3	V
Output Leakage Current * DI-509B; DI-514B; DI-504B * DI-508B; DI-513B; DI-503B.	I <sub>out</sub> (OFF)	V+ = 50V ----- V+ = 80V	V <sub>o</sub> = 50V; V <sub>i</sub> = 0.4V ----- V <sub>o</sub> = 80V; V <sub>i</sub> = 0.4V	0.1	10	μA
Input Current	I <sub>in</sub> (ON)		V <sub>i</sub> = 2.4V	250	400	μA
Supply Current	I+	One Input at 2.4V; Others at 0.4V.	V <sub>i</sub> = 2.4 V; I <sub>o</sub> = 0 V+ = 50V	0.8	1.2	mA

### Typical Application:

